

Product Summary

BV_{DSS}	$R_{DS(ON)}$ Max	I_D $T_C = +25^\circ\text{C}$
100V	1.5m Ω @ $V_{GS} = 10\text{V}$	352A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

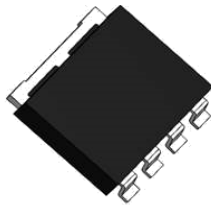
Features and Benefits

- Rated to +175°C – Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production – Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low $R_{DS(ON)}$ – Minimizes Power Losses
- Wettable Flank for Improved Optical Inspection
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An automotive-compliant part is available under a separate datasheet ([DMTH10H1M7SPGWQ](#))**

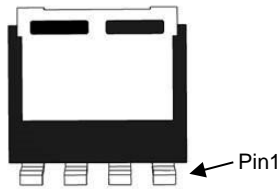
Mechanical Data

- Package: PowerDI®8080-5
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ②3
- Weight: 0.36 grams (Approximate)

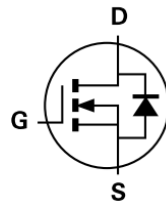
PowerDI8080-5



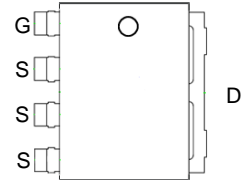
Top View



Bottom View



Internal Schematic



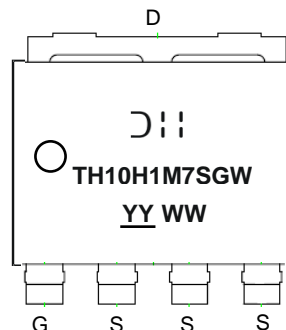
Top View
Pin Configuration

Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
DMTH10H1M7SPGW-13	PowerDI8080-5	2,000	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



DI = Manufacturer's Marking
TH10H1M7SGW = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 25 = 2025)
WW = Week (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6)	T _C = +25°C T _C = +100°C	I _D	352 249	A
Maximum Continuous Body Diode Forward Current (Note 6)		I _S	352	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	1400	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I _{SM}	1400	A
Avalanche Current, L = 1mH		I _{AS}	53	A
Avalanche Energy, L = 1mH		E _{AS}	1404	mJ

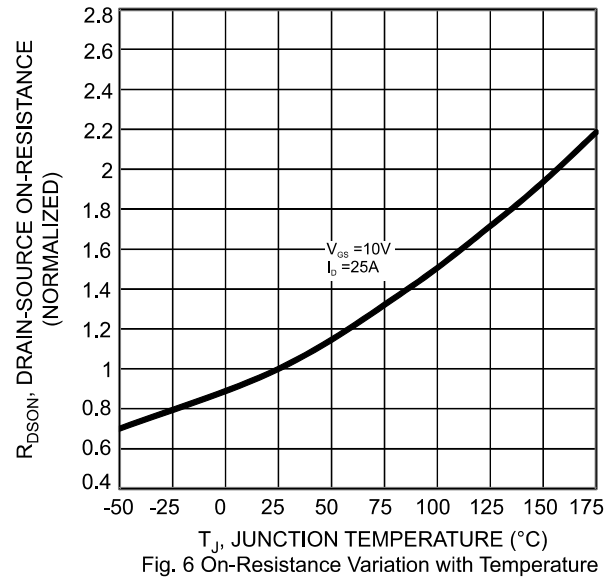
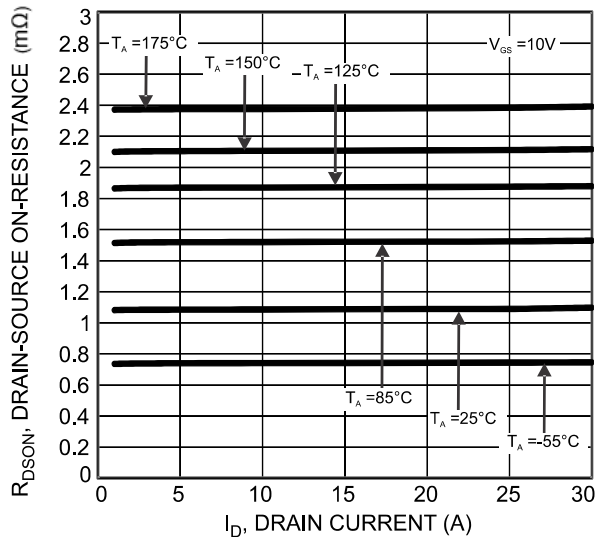
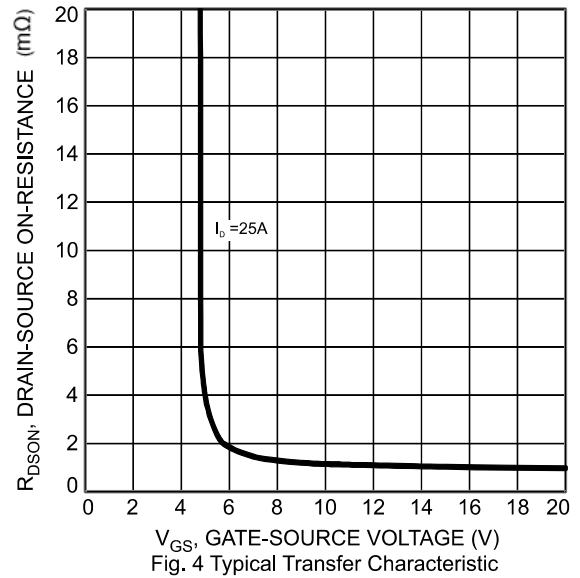
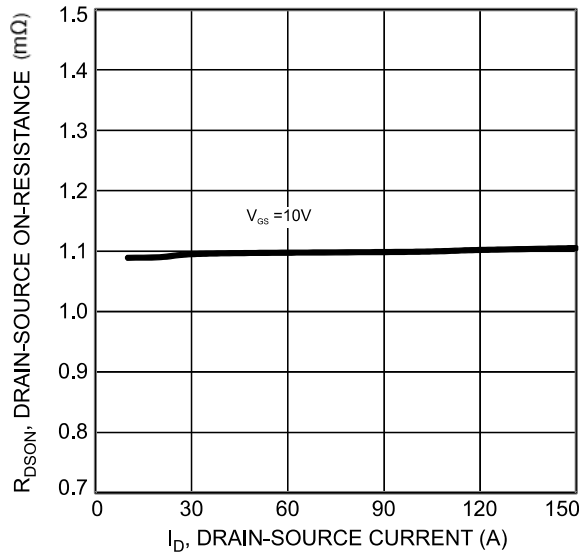
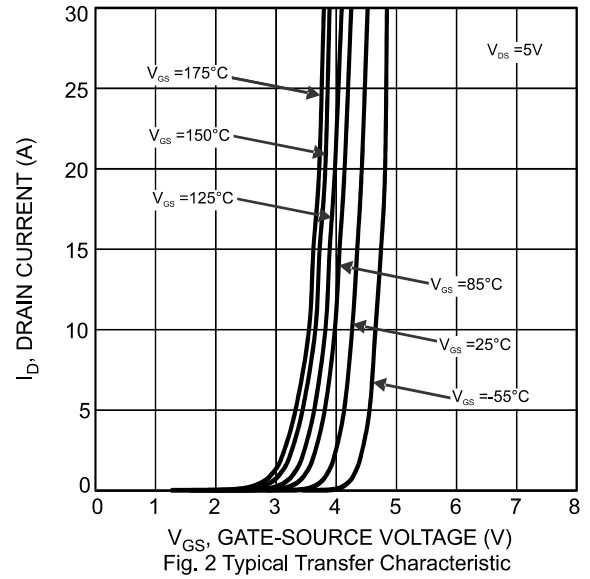
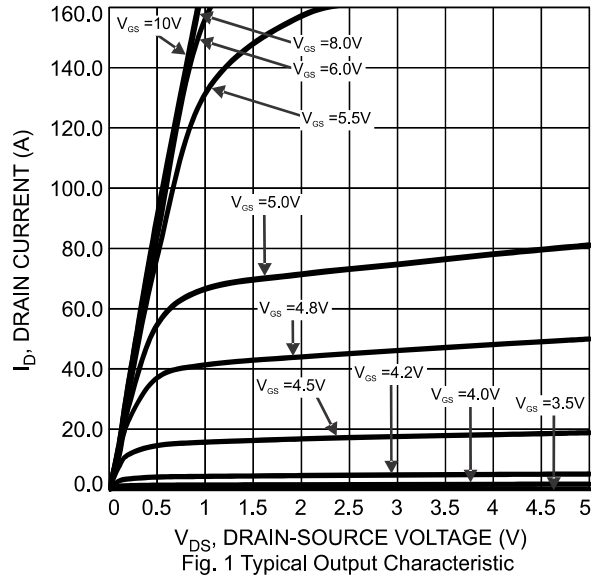
Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	P _D	5	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	30	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	P _D	405	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	0.37	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	100	—	—	V	V _{GS} = 0, I _D = 1mA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	µA	V _{DS} = 80V, V _{GS} = 0
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±20V, V _{DS} = 0
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	2	—	4	V	V _{DS} = V _{GS} , I _D = 250µA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	1.13	1.5	mΩ	V _{GS} = 10V, I _D = 25A
Diode Forward Voltage	V _{SD}	—	0.75	1.2	V	V _{GS} = 0, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	—	10881	—	pF	V _{DS} = 50V, V _{GS} = 0, f = 1MHz
Output Capacitance	C _{oss}	—	3693	—		
Reverse Transfer Capacitance	C _{rss}	—	101	—		
Gate Resistance	R _g	—	0.71	—	Ω	V _{DS} = 0, V _{GS} = 0, f = 1MHz
Total Gate Charge	Q _g	—	171	—	nC	V _{DD} = 50V, I _D = 25A, V _{GS} = 10V
Gate-Source Charge	Q _{gs}	—	51	—		
Gate-Drain Charge	Q _{gd}	—	40	—		
Turn-On Delay Time	t _{D(ON)}	—	28	—	ns	V _{DD} = 50V, V _{GS} = 10V, I _D = 25A, R _G = 3Ω
Turn-On Rise Time	t _r	—	43	—		
Turn-Off Delay Time	t _{D(OFF)}	—	71	—		
Turn-Off Fall Time	t _f	—	54	—		
Body Diode Reverse-Recovery Time	t _{RR}	—	99	—	ns	I _F = 25A, di/dt = 100A/µs
Body Diode Reverse-Recovery Charge	Q _{RR}	—	334	—	nC	

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 - Thermal resistance from junction to soldering point (on the exposed drain pad).
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.



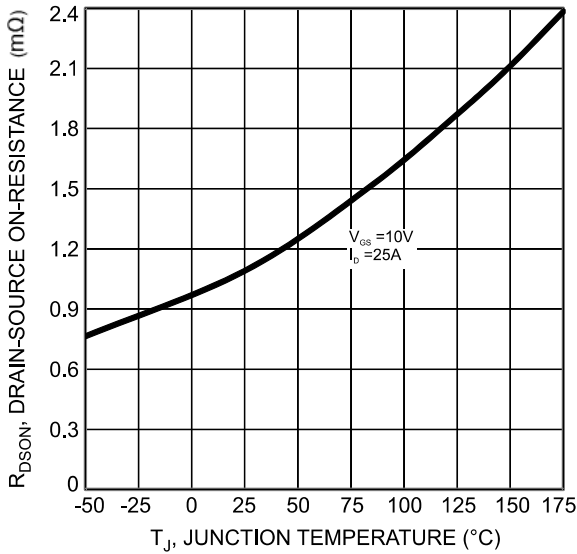


Fig. 7 On-Resistance Variation with Temperature

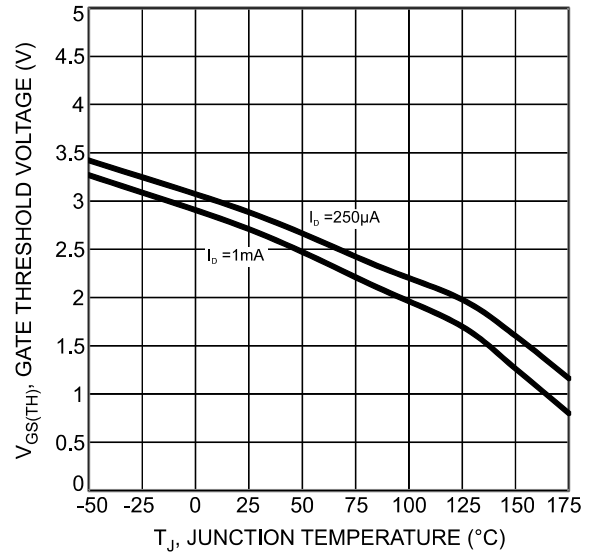


Fig. 8 Gate Threshold Variation vs Junction Temperature

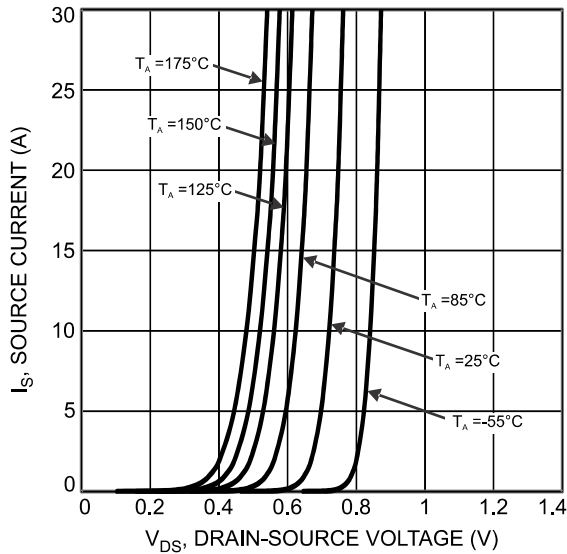


Fig. 9 Diode Forward Voltage vs. Current

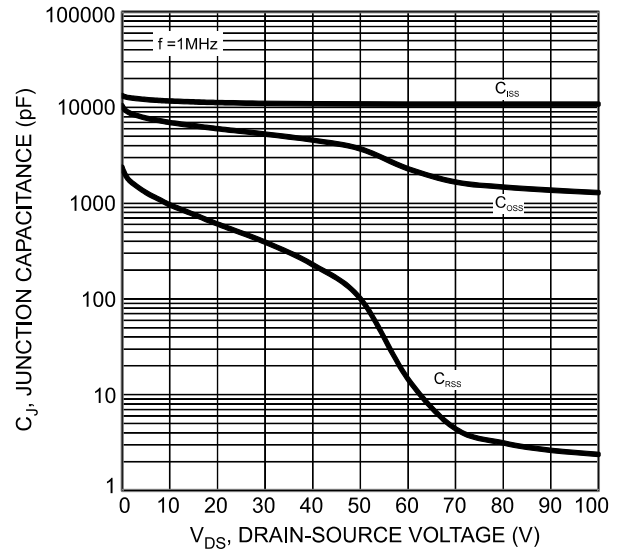


Fig. 10 Typical Junction Capacitance

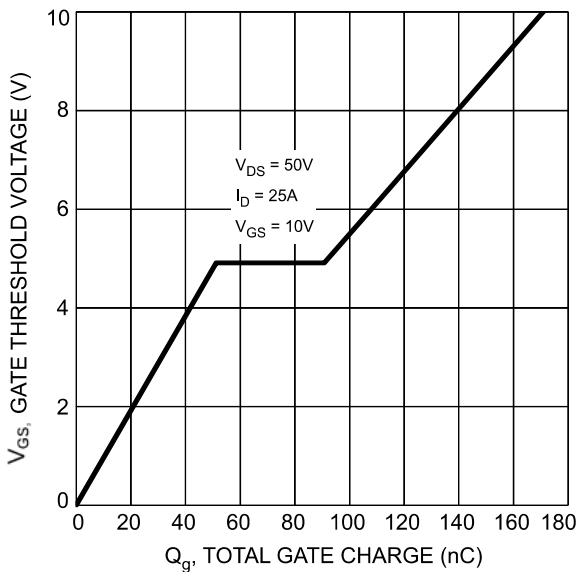


Fig. 11 Gate Charge

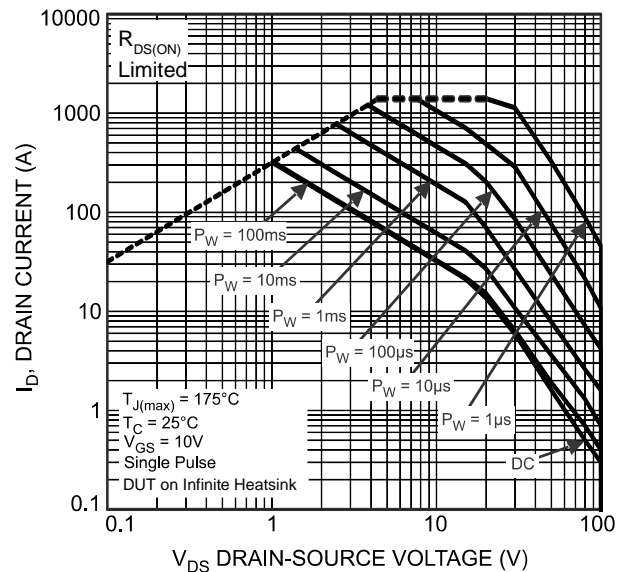


Fig. 12 SOA, Safe Operation Area

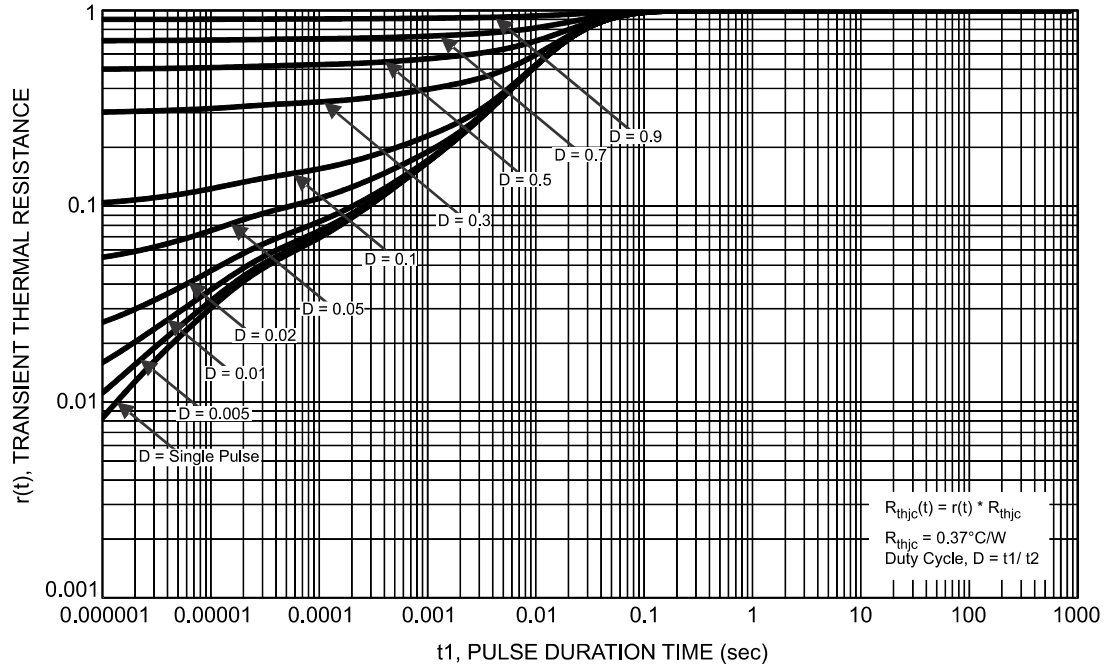
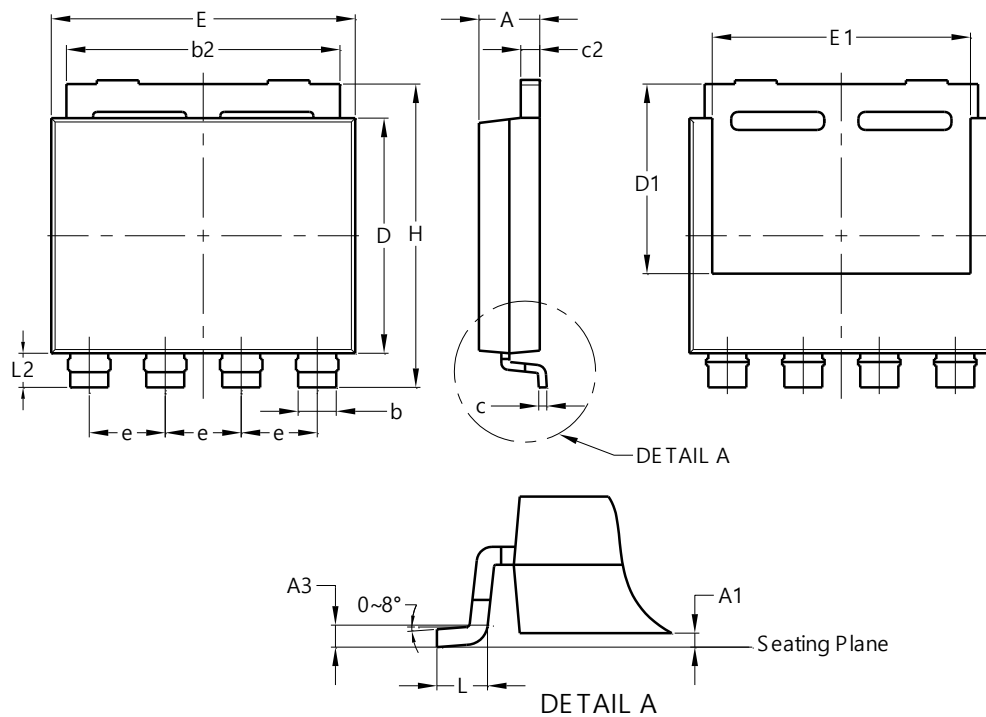


Fig. 13 Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI8080-5

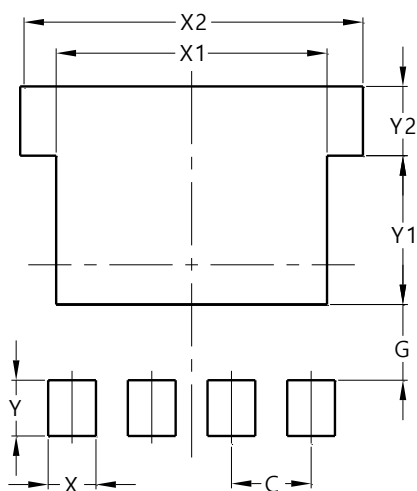


PowerDI8080-5			
Dim	Min	Max	Typ
A	1.50	1.70	--
A1	0.00	0.15	--
A3	--	--	0.25
b	0.90	1.10	--
b2	7.10	7.30	--
c	0.18	0.24	--
c2	0.47	0.57	--
D	6.10	6.30	--
D1	4.90	5.10	--
E	7.90	8.10	--
E1	6.70	6.90	--
e	--	--	2.00
H	7.80	8.10	--
L	0.60	0.80	--
L2	0.90	1.30	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI8080-5



Dimensions	Value (in mm)
C	2.00
G	1.90
X	1.20
X1	6.80
X2	8.60
Y	1.40
Y1	3.74
Y2	1.76

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